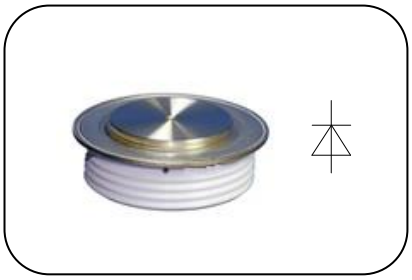
Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

$I_{F(AV)}$	**970 A**
V_{RRM}	**5600~6500 V**
I_{FSM}	**16.5 kA**
I^2t	**1361 10^3A^2S**



SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T_j(°C)	VALUE			UNIT
					Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled,	T_C=100°C	150			970	A
V_{RRM}	Repetitive peak reverse voltage	tp=10ms		150	5600		6500	V
I_{RRM}	Repetitive peak current	At V_{RRM}		150			100	mA
I_{FSM}	Surge forward current	10ms half sine wave V_R=0.6V_{RRM}		150			16.5	kA
I^2t	I^2t for fusing coordination						1361	A^2s*10^3
V_{FO}	Threshold voltage			150			0.91	V
r_F	Forward slope resistance						0.60	mΩ
V_{FM}	Peak forward voltage	I_{FM}=1500A, F=26kN		150			2.15	V
Q_{rr}	Recovery charge	I_{FM}=2000A, tp=2000μs, di/dt=-5A/μs, V_R=50V				3500		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	DC, double side cooled Clamping force 26kN					0.022	°C /W
$R_{th(c-h)}$	Thermal resistance case to heatsink						0.005	
F_m	Mounting force				19		26	kN
T_{stg}	Stored temperature				-40		160	°C
W_t	Weight					440		g
Outline	P52							

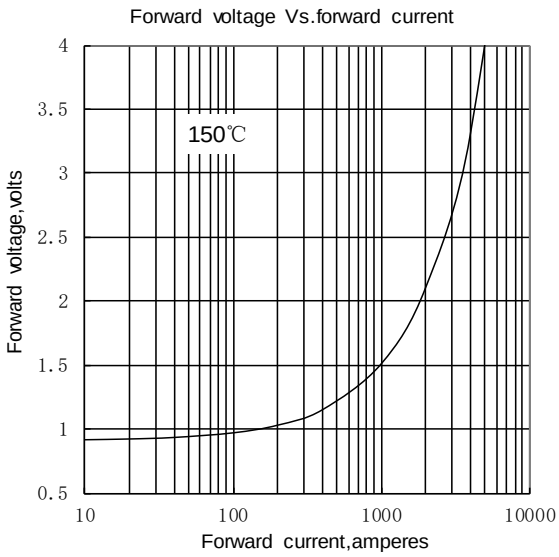


Fig.1

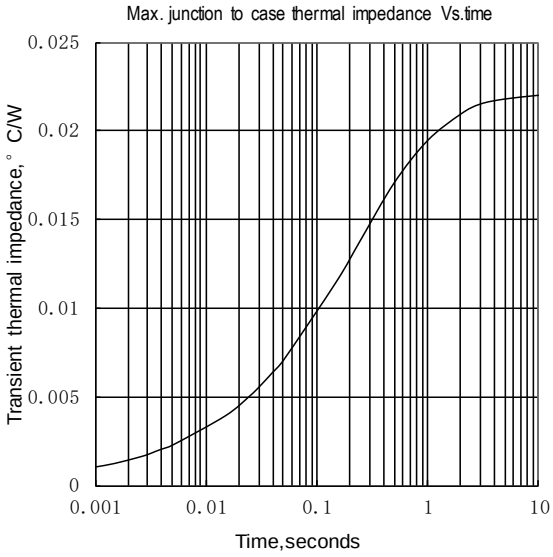


Fig.2

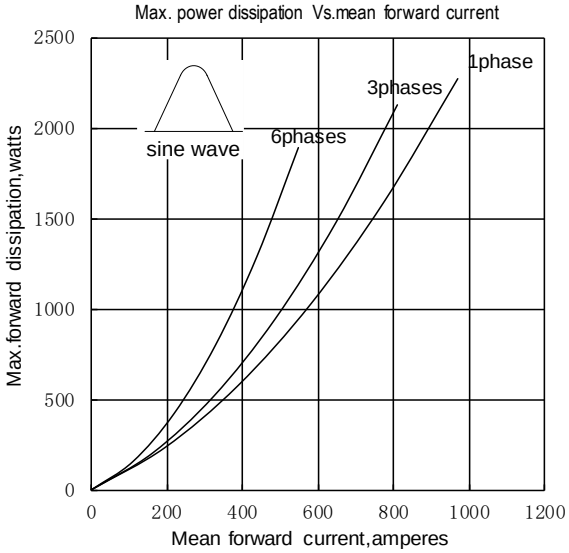


Fig.3

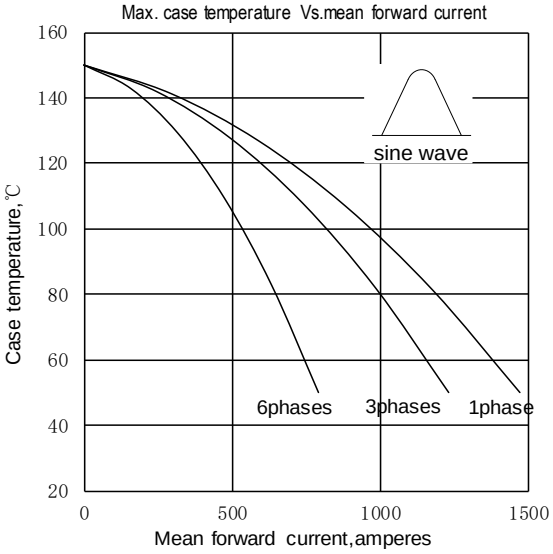


Fig.4

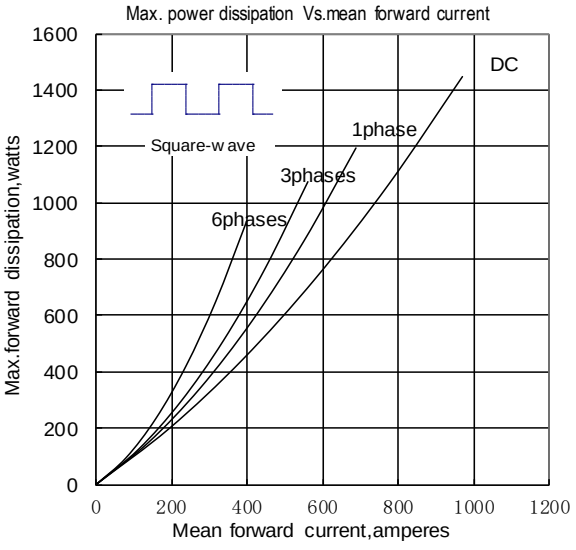


Fig.5

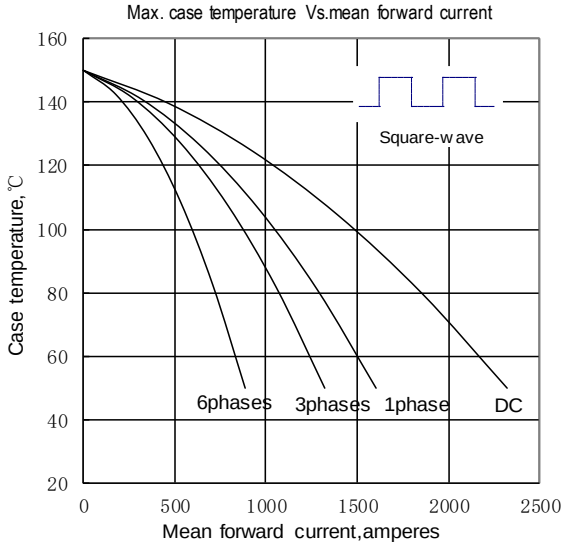


Fig.6

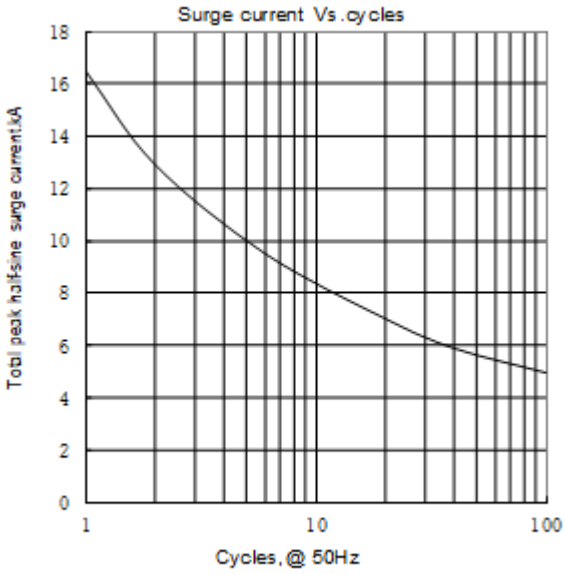
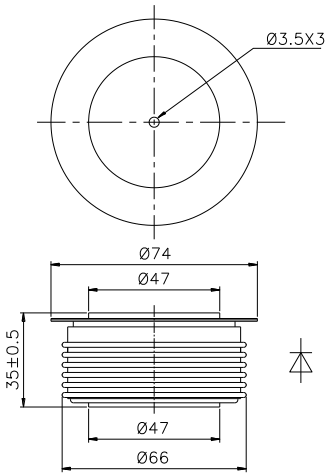


Fig.7



NIps reserves the right to change specifications without notice.